

JA40008000P47; 4 - 8 GHz 50W AMPLIFIER

- Solid-state Class AB design
- Ultrawide-band Operation
- GaN on SiC Transistors
- High reliability and ruggedness
- Forward/Reflected Power Monitorings
- Fast Switching Capability



ELECTRICAL & ENVIRONMENTAL SPECIFICATIONS

Frequency: 4000-8000 MHz

Output Power: 50 W typ. 40 W min.

RF input for Rated Output: -10 dBm typ. Nominal Gain (@ SS input): 60 ± 4 dB typ.

Input VSWR: 2:1 max.

Load VSWR for Survival: ∞:1 (Fully Protected)

Spurious / 2^{nd}&3rd **Harm:** <-60 dBc / < -15&-20 dBc

DC Supply Voltage: 28 V

Enable Speed: 3 µs max.

Operating Case Temp.: -40 °C to 85 °C

External Heatsink Required

Storage Temperature: -40 °C to 85 °C

Shock: MIL-STD-810F/G
Vibration: MIL-STD-810F/G

INTERFACES

RF Input: SMA Female

RF Output: SMA Female

9-PIN DSUB: 1) GND

2) GND

3) 28 V

4) Enable

5) Reverse Power (0 - 3V Analog)

6) GND 7) 28 V

8) 28 V

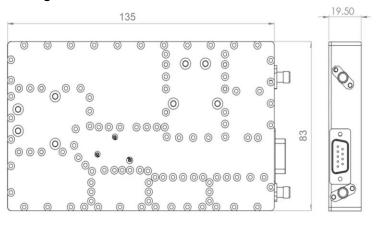
9) Forward Power (0 - 3V Analog)

MECHANICAL SPECIFICATIONS

Size (mm): 135 × 83 × 19.5 (inch): 5.3 x 3.27 x 0.77

Weight: 600 gr.

Plating: Yellow Chromate



GENERAL DESCRIPTION

is a RFTR's JA40008000P47 reliable ultrawide-band 50W power amplifier operating between 4000-8000 MHz and suitable for CW or Pulsed waveforms. This amplifier can be used in different applications such as radars, datalinks, mobile jamming or UAVs in S and C bands. JA40008000P47 offers forward-reverse power monitoring and survives under ∞:1 load VSWR condition. The PΑ can enabled/disabled as fast as 3 µs that makes it suitable for power saving during pulsed applications.

JA40008000P47 is designed with the components that do not require any export license.

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